Part Number: XRNI12W

Phototransistor

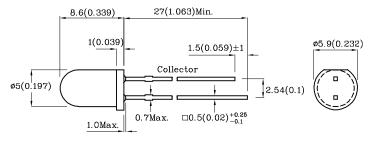
Features

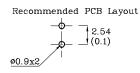
- Radial / Through hole package
- Reliable & robust
- Low power consumption
- Available on tape and reel
- Water clear lens
- RoHS Compliant





Package Schematics





Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is $\pm 0.25(0.01")$ unless otherwise noted.
- 3. Specifications are subject to change without notice.

Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Min.	Typ.	Max.	Unit	Test Condiction
VBR CEO	Collector-to-Emitter Breakdown Voltage	30	-	-	V	$I_{\rm C}=100\mu A$ $E_{\rm e}=0mW/cm^2$
VBR ECO	Emitter-to-Collector Breakdown Voltage	5	-	-	V	$\begin{split} I_{\scriptscriptstyle E} &= 100 \mu A \\ E_{e} &= 0 mW/cm^2 \end{split}$
VCE(SAT)	Collector-to-Emitter Saturation Voltage	-	-	0.8	V	$\begin{split} I_{\mathrm{C}} &= 2 m A \\ E_{\mathrm{e}} &= 20 m \text{W/cm}^2 \end{split}$
ICEO	Collector Dark Current	-	-	100	nA	$V_{\rm CE} = 10 V \\ E_{\rm e} = 0 mW/cm^2$
Tr	Rise Time (10% to 90%)	-	15	ı	μs	V_{CE} = 5V I_{C} = 1mA R_{L} = 1K Ω
${ m TF}$	Fall Time (90% to 10%)	-	15	-	μs	
I(ON)	On State Collector Current	0.5	2.5	1	mA	$V_{\text{CE}} = 5V$ $E_{\text{e}} = 1 \text{mW/cm}^2$ $\lambda = 940 \text{nm}$
$\lambda_{0.1}$	Range of Spectral Bandwidth	420	-	1120	nm	-
λ_{p}	Wavelength of Peak Sensitivity	-	940	-	nm	-

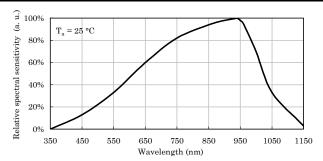
Absolute Maximum Ratings at TA=25°C

Parameter	Maximum Ratings		
Collector-to-Emitter Voltage	30V		
Emitter-to-Collector Voltage	5V		
Power Dissipation at (or below) 25°C Free Air Temperature	100mW		
Operating / Storage Temperature Range	-40 ∼ +85°C		
Lead Solder Temperature (>5mm for 5sec)	260°C		

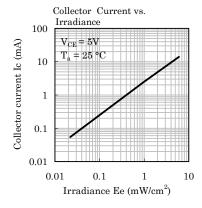
A Relative Humidity between 40% and 60% is recommended in ESD-protected work areas to reduce static build up during assembly process (Reference JEDEC/JESD625-A and JEDEC/J-STD-033)







Relative Intensity Vs. CIE Wavelength



Collector Dark Current vs.

Ambient Temperature

VCE = 20V

25

50

Ambient temperature (°C)

Ee = 0

1000

100

10

1

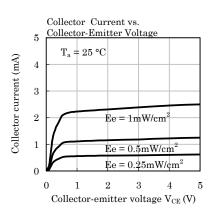
0.1

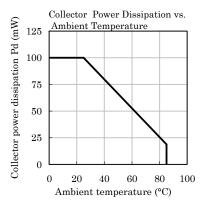
Collector dark current (nA)

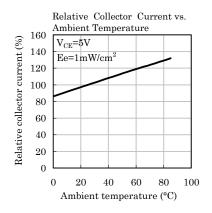


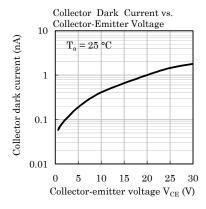
100

75

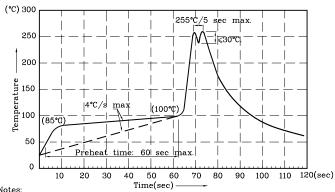












- Notes.

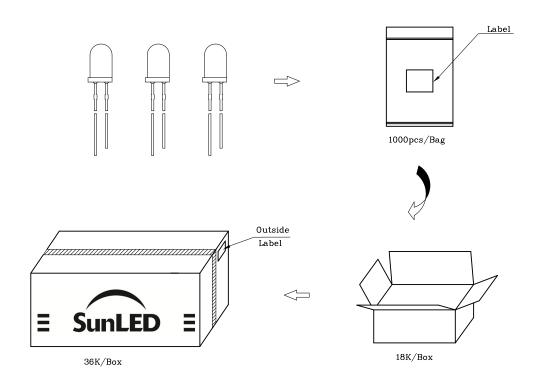
 1. Recommend pre-heat temperature of 105°C or less (as measured with a thermocouple attached to the LED pins) prior to immersion in the solder wave with a maximum solder bath temperature of 260°C

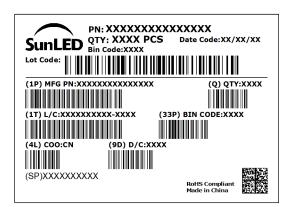
 2. Peak wave soldering temperature between 245°C ~ 255°C for 3 sec
- (5 sec max).
- 3.Do not apply stress to the epoxy resin while the temperature is above 85°C. 4. Fixtures should not incur stress on the component when mounting and during soldering process.
 5.SAC 305 solder alloy is recommended.
 6. No more than one wave soldering pass.





PACKING & LABEL SPECIFICATIONS





TERMS OF USE

- 1. Data presented in this document reflect statistical figures and should be treated as technical reference only.
- 2. Contents within this document are subject to improvement and enhancement changes without notice.
- 3. The product(s) in this document are designed to be operated within the electrical and environmental specifications indicated on the datasheet. User accepts full risk and responsibility when operating the product(s) beyond their intended specifications.
- 4. The product(s) described in this document are intended for electronic applications in which a person's life is not reliant upon the LED. Please consult with a SunLED representative for special applications where the LED may have a direct impact on a person's life.
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- 6. The contents within this document may not be altered without prior consent by SunLED.
- 7. Additional technical notes are available at https://www.SunLEDusa.com/TechnicalNotes.asp

XDSA8078 V8 Layout: Maggie L

P. 3/3